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Benefits from below: Silicon supplementation maintains legume productivity under predicted climate change scenarios

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The authors declare that the research was conducted in the absence of any commercial or financial relationships that could be construed as a potential conflict of interest.

Author contribution statement

The authors are grateful to James Stockdale for conducting the Si analysis and the 2015 class of the Invertebrate Biology (300918) unit for assistance in conducting the experiment. This research was part of a Hawkesbury Institute for the Environment exchange program awarded to SEH and SNJ.

Keywords

alfalfa, Aphids, Atmospheric change, Climate Change, Global Warming, silica, Silicon

Abstract

Word count: 293

Many studies demonstrate that elevated atmospheric carbon dioxide concentrations (eCO₂) can promote root nodulation and biological nitrogen fixation (BNF) in legumes such as lucerne (Medicago sativa). But when elevated temperature (eT) conditions are applied in tandem with eCO₂, a more realistic scenario for future climate change, the positive effects of eCO₂ on nodulation and BNF in M. sativa are often much reduced. Silicon (Si) supplementation of M. sativa has also been reported to promote root nodulation and BNF, so could potentially restore the positive effects of eCO₂ under eT. Increased nitrogen availability, however, could also increase host suitability for aphid pests, potentially negating any benefit. We applied eCO₂ (+240ppm) and eT (+4°C), separately and in combination, to M. sativa growing in Si supplemented (S+) and un-supplemented soil (S-) to determine whether Si moderated the effects of eCO₂ and eT. Plants were either inoculated with the aphid Acyrthosiphon pisum or insect-free. In S-soils, eCO₂ stimulated plant growth by 67% and nodulation by 42% respectively, whereas eT reduced these parameters by 26% and 48% respectively. Aphids broadly mirrored these effects on S-plants, increasing colonization rates under eCO₂ and performing much worse (reduced abundance and colonization) under eT when compared to ambient conditions, confirming our hypothesized link between root nodulation, plant growth and pest performance. Examined across all CO₂ and temperature regimes, Si supplementation promoted plant growth (+33%), and root nodulation (+50%). Acyrthosiphon pisum abundance declined sharply under eT conditions and was largely unaffected by Si supplementation. In conclusion, supplementing M. sativa with Si had consistent positive effects on plant growth and nodulation under different CO₂ and temperature scenarios. These findings offer potential for using Si supplementation to maintain legume productivity under predicted climate change scenarios without making legumes more susceptible to insect pests.

Ethics statements

(Authors are required to state the ethical considerations of their study in the manuscript, including for cases where the study was exempt from ethical approval procedures)

Does the study presented in the manuscript involve human or animal subjects: No
Benefits from below: Silicon supplementation maintains legume productivity under predicted climate change scenarios

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Running title: Silicon modifies legume responses to climate change

Abstract
Many studies demonstrate that elevated atmospheric carbon dioxide concentrations (eCO2) can promote root nodulation and biological nitrogen fixation (BNF) in legumes such as lucerne (Medicago sativa). But when elevated temperature (eT) conditions are applied in tandem with eCO2, a more realistic scenario for future climate change, the positive effects of eCO2 on nodulation and BNF in M. sativa are often much reduced. Silicon (Si) supplementation of M. sativa has also been reported to promote root nodulation and BNF, so could potentially restore the positive effects of eCO2 under eT. Increased nitrogen availability, however, could also increase host suitability for aphid pests, potentially negating any benefit. We applied eCO2 (+240ppm) and eT (+4ºC), separately and in combination, to M. sativa growing in Si supplemented (Si+) and un-supplemented soil (Si-) to determine whether Si moderated the effects of eCO2 and eT. Plants were either inoculated with the aphid Acyrthosiphon pisum or insect-free. In Si- soils, eCO2 stimulated plant growth by 67% and nodulation by 42%, respectively, whereas eT reduced these parameters by 26% and 48%, respectively. Aphids broadly mirrored these effects on Si- plants, increasing colonization rates under eCO2 and performing much worse (reduced abundance and colonizaton) under eT when compared to ambient conditions, confirming our hypothesized link between root nodulation, plant growth and pest performance. Examined across all CO2 and temperature regimes, Si supplementation promoted plant growth (+93%), and root nodulation (+50%). Acyrthosiphon pisum abundance declined sharply under eT conditions and was largely unaffected by Si supplementation. In conclusion, supplementing M. sativa with Si had consistent positive effects on plant growth and nodulation under different CO2 and temperature scenarios. These findings offer potential for using Si supplementation to maintain legume productivity under predicted climate change scenarios without making legumes more susceptible to insect pests.

Keywords: alfalfa, aphids, atmospheric change, climate change, global warming, silica, silicon
Introduction

Projected increases in atmospheric carbon dioxide (CO$_2$) have been shown experimentally to stimulate biological nitrogen fixation (BNF) in legumes (Soussana and Hartwig, 1996; Zanetti et al., 1996; Hungate et al., 1999; Edwards et al., 2006; Lam et al., 2012). These effects are strongest immediately after exposure to elevated CO$_2$ (eCO$_2$) (Hungate et al., 2004) and when other nutrients (especially phosphorus) are not limiting (Rogers et al., 2009). Elevated CO$_2$ (eCO$_2$) can promote BNF via several mechanisms, including larger numbers of N$_2$ fixing symbiotic bacteria in the rhizosphere (Schortemeyer et al., 1996), increased numbers of nodules which house N$_2$ fixing rhizobia bacteria (Ryle and Powell, 1992) and enhanced nitrogenase activity (Norby, 1987). Broadly speaking, eCO$_2$ allows legumes to increase rates of photosynthesis and allocate more carbon belowground to support increased root nodulation and therefore BNF (Aranjuelo et al., 2014).

Researchers are becoming increasingly aware of the importance of testing multiple environmental change factors because they are predicted to occur concurrently and often have either synergistic or antagonistic impacts on one another (Robinson et al., 2012; Johnson and Jones, 2017). Climate models predict, for instance, that air temperatures will increase in tandem with increases in atmospheric CO$_2$ and warmer temperature may negate any positive impacts of eCO$_2$ on plant growth (Newman et al., 2011). This may be particularly true in legume systems because higher temperatures can have inhibitory effects on BNF due to the relatively low tolerance of N$_2$-fixing bacteria to higher temperatures (Zahran, 1999; Whittington et al., 2013; Aranjuelo et al., 2014). The optimal temperature for root nodule symbiosis for temperate legumes is thought to be around 15-25°C, above which detrimental effects can become evident (Aranjuelo et al., 2014). Elevated temperature (eT) can directly hinder the development and functionality of root nodulation and accelerate nodule senescence (Piha and Munns, 1987; Aranjuelo et al., 2006). In addition, eT can inhibit nodulation via plant-mediated mechanisms, including reduced root hair formation, fewer nodulation sites and poorer adherence of bacteria to root hairs (Hungria and Franco, 1993; Hungria and Vargas, 2000; Aranjuelo et al., 2014).

Soil conditions play an important role in determining the extent to which eCO$_2$ and eT affect root nodulation in legumes (Aranjuelo et al., 2014). Several studies report that supplementation of soil silicon (Si) levels promotes growth in legumes (Horst and Marschner, 1978; Miyake and Takahashi, 1985; Guo et al., 2006; Johnson et al., 2017), though we know less about the functional role of Si in legumes compared to other plant families such as the Poaceae (Epstein, 1999; Cooke and Leishman, 2011). Moreover, Si supplementation can increase rates of root nodulation and symbiosis with nitrogen fixing bacteria (Nelwamondo and Dakora, 1999; Mali and Aery, 2008). However, how these positive effects of Si on nodulation are affected by eCO$_2$ or eT, alone or in combination, have not yet been addressed. If Si could maintain nodulation rates under future climate change scenarios, such as eT, which usually decrease it, then such supplementation could be important in the mitigation of climate change impacts on agriculture.

While rhizobial colonization promotes legume growth and vigour, this improved host quality can also increase susceptibility to belowground (Quinn and Hower, 1986; Gerard, 2001; Johnson and McNicol, 2010) and aboveground insect herbivores (Dean et al., 2009; Kempel et al., 2009; Katayama et al., 2010; Dean et al., 2014; Whitaker et al., 2014). Beneficial effects of rhizobia on herbivores most likely arise through increased provision of nitrogen, which is frequently limiting in insect herbivore diets (Mattson, 1980). Increased provision of nitrogen may, however, allow plants to invest in plant defenses with negative impacts on
herbivores (Pineda et al., 2010; Brunner et al., 2015). While Si supplementation usually
increases plant resistance to herbivores (mainly reported in the Poaeceae; Reynolds et al.,
2009), it may also indirectly increase susceptibility to herbivores via increases in legume
growth and nutritional quality (Johnson et al., 2017).

The objective of this study was to determine how eCO\(_2\) and eT, acting alone and in
combination, affected root nodulation and plant growth in \(M.\ sativa\) in untreated (Si-) and Si
supplemented (Si+) soil. We additionally aimed to establish whether these factors affected
the abundance and colonization success of an insect herbivore (the aphid \(Acyrthosiphon\)
\(pisum\)). We hypothesised that eCO\(_2\) increases growth and root nodulation in \(M.\ sativa\) but eT
negates these effects. Si supplementation increases nodulation, even under eT, and therefore
maximises plant growth regardless of CO\(_2\) and temperature conditions. We hypothesized that
aphid abundance would be positively linked to plant growth and nodulation, whether driven
by Si supplementation or changes in CO\(_2\) and temperature conditions.

Methods and Materials

Insect cultures and plant material

Four \(Acyrthosiphon\ pisum\) cultures were established from a single parthenogenetic adult
female collected from a pasture containing grasses and legumes, including lucerne, at the
Hawkesbury Campus of the Western Sydney University, NSW (latitude \(-33.608847,\)
longitude 150.747016). Cultures were maintained on propagated lucerne (\(M.\ sativa\) L.) plants
(Sequel cultivar) in each of the four CO\(_2\) and temperature combinations (conditions below)
for at least six generations (c. 7 weeks) prior to the experiment. For the experiment, \(M.\ sativa\)
(Sequel) were grown from seed (Seedmark, Adelaide, South Australia) in glasshouse rooms
receiving supplemental light (15:9 light:dark) under the same conditions. Plants were grown
in 70 mm diameter pots containing c. 700g of soil excavated from the Hawkesbury campus of
Western Sydney University (location as above). The soil is typified as low-fertility sandy
loam in the Clarendon Formation (Chromosol) (Barton et al., 2010), which has low
bioavailable Si content of 10-17 mg kg\(^{-1}\) (Johnson et al., 2017).

Growth conditions and experimental procedures

Eighty lucerne plants were grown in each of four CO\(_2\) and temperature-controlled glasshouse
chambers (320 plants in total) using a fully factorial design of ambient CO\(_2\) (aCO\(_2\); 400 µmol
mol\(^{-1}\)) and eCO\(_2\) (640 µmol mol\(^{-1}\)) at ambient (aT) and elevated temperature (ambient + 4°C;
eT). aT was set at 26/18°C day/night representing the average daily temperature (November
to May) over the past 30 years for Richmond, NSW (Australian Bureau of Meteorology). eT
(30/22 °C day/ night) replicated the maximum predicted temperature increase for this region
within this century (CSIRO, 2007-2016). Environmental conditions were monitored
continuously throughout the experiment and temperature readings were verified with portable
temperature loggers. To minimize ‘chamber effects’ associated with using four chambers,
plants were circulated within each chamber every five days (apart from when plants were
inoculated with aphids to avoid dislodgement of the insects) and chambers were swapped
every c. 10 days by transferring plants between chambers and adjusting the environmental
conditions accordingly. While this does not eliminate pseudoreplication, using this approach
in these chambers has provided matching empirical results to fully replicated experiments,
whether using multiple chamber replicates or multiple experimental runs (Johnson et al.,
2016b).

Plants were irrigated with c. 70 ml of tap water (Si 3ppm) three times a week. After growing
for a further two weeks, half (40) of the plants continued to receive tap water (Si- plants or
Si- soil hereafter) at the same intervals while the other half (selected at random) received 70 ml of 500 mg l\(^{-1}\) soluble silica in the form of NaSiO\(_3\).9H\(_2\)O three times a week (Si+ plants or Si+ soil hereafter). When plants were six weeks old, 20 of the plants receiving the Si supplementation and 20 of the plants receiving tap water (selected at random) were inoculated with two teneral adult *A. pisum*. White mesh (organza) bags (125 x 170 mm) were applied tightly around the rim of all pots confining aphids to their allocated plants. After two weeks, bags were removed aphids counted (including colonization success; at least one aphid being present). Plants were cleaned free of soil with water before and the number of active (pink) root nodules quantified. Maximum rooting depth was also quantified to provide a rudimentary measure of nodule density in order to give an indication as whether changes in nodule abundance were a function of root growth or nodule density on the roots (i.e. nodules per unit of root growth). Plants were freeze dried for 48 hr and weighed. Leaves were separated from the stems and ball-milled to a fine power prior to analysis for Si concentrations.

**Foliar Si analysis**

It was necessary to pool foliar samples (2-3 plants per sample), giving nine replicates of each treatment combination (CO\(_2\), temperature, Si application and aphid inoculation). Foliar Si concentrations were analyzed with X-ray fluorescence spectrometry using the method described by Reidinger, Ramsey & Hartley (2012). In summary, plant material was ground to a fine powder and pressed into 13mm-diameter pellets. Foliar Si concentration was determined using a Niton XL3t XRF analyzer (Thermo Fisher Scientific, Inc., MA, USA), for a measurement time of 30 seconds. Results we expressed as foliar Si concentration (as % of dry mass), calibrated against plant-certified reference material of known Si content (Garbuzov et al., 2011).

**Statistical analysis**

Goodness-of-fit tests, using the ‘goodfit’ function in the vcd package (Friendly, 2000), were employed to determine which distributions best described the data. Plant dry mass and nodule density were transformed (logarithm and square-root, respectively) prior to analysis to meet model assumptions and give residual diagnostic plots which fitted a normal distribution and showed least heteroscedasticity. Plant dry mass and nodule density were analyzed using analysis of variance with CO\(_2\), temperature, aphid presence and Si supplementation included as fixed effects individually and in interaction with one another. Root nodule counts and aphid abundance were analyzed with generalized linear models with negative binomial error structures and log-link function using the same configuration of fixed effects as above. Aphid colonization success was analyzed in the same way but with binomial error structure and logit link function. Statistical tests of plant mass and nodulation were conducted on data collectively, before repeating the tests separately for Si- and Si+ plants since there were significant interactions between Si treatment and environmental treatments. Where non-significant effects were observed in full models (i.e. all factors included), non-significant factors were removed to determine whether this affected model inferences with more parsimonious models (e.g. fewer multi-way interaction terms were included in the model) – see Table S1 All analysis was conducted in the R statistical package.

**Results**

Plant growth was stimulated by eCO\(_2\) and Si supplementation by 41% and 93%, respectively, (Fig. 1; Table 1). In contrast, eT and aphid presence depressed plant growth by 13% and 17%, respectively (Fig. 1; Table 1). Temperature depressed plant growth in Si- soil (Fig. 1A),
but not in Si+ soil (Fig. 1B), though there was an interactive effect of CO$_2$ and temperature in the latter, with eCO$_2$ promoting plant growth more at eT than under aT conditions (Fig. 1B).

Root nodulation increased when plants grew under eCO$_2$ (+27%) and Si+ conditions (+50%) (Fig. 2, Table 1), but eT caused significant declines in nodulation (-32%). In Si- soil, root nodulation patterns generally mirrored changes in plant growth (Fig. 1A and 2A, respectively). Levels of root nodulation were universally high in plants growing in Si+ soil and other factors (CO$_2$, temperature and aphid presence) no longer had significant impacts (Fig. 2B). This was particularly true for the negative impacts of eT, which was reversed under Si+ conditions, reflected by the significant interaction of these treatments (Table 1, Fig 2).

Our rudimentary estimate of nodule density (nodes per unit of root depth) suggested this was not affected by CO$_2$ (other than the weak interaction described below) but declined by 25% under eT (Table S1, Fig. S1). Nodule density increased (c. +45%) under Si+ conditions and, like nodule abundance, there was a significant interaction between Si treatment and temperature, whereby negative effects of eT were revered under Si+ conditions (Table S1, Fig. S1). There was a very weak interaction between Si, aphids and CO$_2$.

Si concentration in the foliage was unaffected by CO$_2$, temperature and aphid presence, though unexpectedly there was a small but significant decline in foliar Si concentrations when growing in Si+ soil (Fig. 3, Table 1).

Aphid abundance was not significantly affected by eCO$_2$ (Fig. 4), although colonization success increased by 14% under eCO$_2$ (Table 2). In contrast, eT caused substantial declines (-65%) in aphid abundance and reduced their ability to colonise plants, falling by 48% and 43% on Si- and Si+ plants, respectively (Table 2). Aphid populations at eT were similar regardless of Si treatments. In short, aphid abundance was always lowest at 30ºC and Si promotion of plant growth and nodulation was decoupled from aphid performance, such that Si+ conditions led to increased nodulation (and potentially BNF) without increasing aphid numbers.

The key findings of this study are summarized in Fig. 5 which held true when non-significant terms were dropped from models for parsimony (see Table S2). Panels A, B and C in Fig. 5 show how aphid abundance mirrors patterns of nodulation and plant growth in non-supplemented soils, but this becomes decoupled in Si+ soils, where Si supplementation restores the fertilising effects of eCO$_2$ on M. sativa at higher temperatures without affecting aphid populations.

Discussion

Results from this study suggest that Si supplementation may mitigate the negative impacts of eT on plant growth in M. sativa which was potentially due to stimulation of root nodulation, despite the reduction in nodulation at higher temperatures reported in previous studies (e.g. Ryalls et al., 2013b). Even more advantageously, this increased nodulation did not increase susceptibility to an aphid pest at eT, which had previously been observed for Si-induced increases in nodulation at ambient temperatures (Johnson et al., 2017).

Aphid abundance was strongly suppressed by eT and this most likely explains why aphids did not benefit from increases in plant growth and nodulation that arose under Si+ conditions under eT. While aphid numbers often increase with higher temperatures via faster development and increased fecundity, this increase ceases abruptly over a certain temperature threshold because of the adverse effects on, for example, embryo development and
maturation (Ryalls and Harrington, 2017). This temperature threshold depends on species, aphid biotype and geographical region (Awmack and Leather, 2007). *Acyrthosiphon pisum* has adapted to the warmer climate of Australia since introduction in the 1970s (Ryalls et al., 2013a). Some populations are able to function at temperatures above 35°C, although their optimum temperature is said to be c. 20-25°C (Ryalls, 2016) and temperatures above 28°C are likely to reduce aphid growth and development (Bieri et al., 1983; Lamb and MacKay, 1988; Mackay et al., 1993). Aphid biotypes with certain secondary bacterial endosymbionts may cope better with higher temperatures, however, since there have been several reports of endosymbionts alleviating the effects of heat stress (Montllor et al., 2002; Russell and Moran, 2005; Dunbar et al., 2007). To our knowledge, studies have not yet addressed how bacterial endosymbionts might change in response to eCO$_2$ and eT but endosymbionts could partially facilitate adaptation to climate and atmospheric change (Sun et al., 2016; Ryalls and Harrington, 2017).

Several studies using temperature gradient greenhouses have examined the impacts of eCO$_2$ and eT on legume performance, including root nodulation (Aranjuelo et al., 2006; Erice et al., 2006; Erice et al., 2007; Aranjuelo et al., 2008). These studies report a general trend for eCO$_2$ promoting nodulation, but only at the elevated experimental temperatures. This was probably because the elevated temperature range used in experiments (c. 24°C; Aranjuelo et al., 2008) was still within the optimal range (19-25°C) for nodulation in temperate legumes, so inhibitory effects of temperature on nodulation wouldn’t necessarily have occurred (Aranjuelo et al., 2014). When temperature was elevated beyond 25°C to 30°C, root nodulation in *M. sativa* has been reported to decrease by 22% under ambient CO$_2$ (aCO$_2$) and by 56% under eCO$_2$ (Ryalls et al., 2013b).

Despite increasing evidence that the effects of eCO$_2$ are often modified by eT, and *vice versa*, comparatively few studies manipulate both factors in tandem (Robinson et al., 2012). In the present study we established that positive impacts of eCO$_2$ on plant traits were not seen to the same extent when eT conditions were applied. This study therefore lends support to the notion that, wherever feasible, multiple environmental factors should be tested (Newman et al., 2011; Lindroth and Raffa, 2016). Crucially, Si supplementation had consistently stronger impacts on plant traits across a range of environmental conditions and regardless of whether plants were challenged by herbivores.

A counterintuitive finding of the study was that Si supplementation actually reduced concentrations of Si in the foliage. Si may have promoted plant growth to such an extent that Si became ‘diluted’ in foliage, or else had not had time to accumulate in plant tissues over the duration of the study. A similar trend in foliar Si was previously observed in this system however, associated with rapid plant growth, increases in root nodulation and synthesis of amino acids (Johnson et al., 2017). In addition to any increased nutritional value, the lower concentrations of Si in foliage of Si+ plants may explain why Si supplementation did not increase plant resistance to aphids.

Our results demonstrate conclusively the benefits of Si supplementation for root nodulation: root nodule abundance was always increased in plants growing in Si+ soil and other factors, whether CO$_2$, temperature and aphid presence no longer had significant impacts on nodule abundance. The mechanisms by which Si is so effective at promoting nodulation are not well understood, but could include changes in soil conditions, increased root growth (and potential invasion sites), higher abundance of bacteroids and symbiosomes, together with the synthesis of compounds that upregulate nodulation genes (as discussed by Johnson et al., 2017). The
increased nodule density reported in the present study tentatively suggests that greater nodule abundance was not merely a function of increased root growth. Further work is needed, but Si could provide a useful tool for mitigating some of the negative impacts of climate change on crop production – in this instance maintaining nodulation rates of *M. sativa* in warmer climates. Moreover, other studies suggest Si could redress negative effects of eCO2 on plant-herbivore interactions. For example, herbivore damage to roots of sugarcane was exacerbated under eCO2 conditions, but application of Si reversed these effects and stimulated crop growth (Frew et al., 2017). Intervention strategies could include targeted application of Si (e.g. furnace slag), selection of plant lines that naturally take up large amounts of Si (McLarnon et al., 2017) and remediation of soils deficient in bioavailable Si (silicic acid) (Guntzer et al., 2012; Johnson et al., 2016a).

**Acknowledgements**

The authors are grateful to James Stockdale for conducting the Si analysis and the 2015 class of the Invertebrate Biology (300918) unit for assistance in conducting the experiment. This research was part of a Hawkesbury Institute for the Environment exchange program awarded to SEH and SNJ.

**Authors’ contributions**

SNJ, JMWR, AF and ANG. conceived the experimental design. SNJ, JMWR, AF and ANG acquired and processed data with SEH undertaking Si analysis. JMWR analyzed the data and all authors contributed to the interpretation and drafting of the manuscript.

**References**


Ryalls, J.M.W., and Harrington, R. (2017). "Climate and atmospheric change impacts on aphids as vectors of plant diseases," in Global Climate Change and Terrestrial...


Figure Legends

**Fig. 1.** Impacts of CO\(_2\), temperature and aphid presence on dry mass of *M. sativa* when growing in (A) non-supplemented and (B) Si supplemented soil. Mean values ± standard error shown (N = 20) with statistically significant effects indicated *P* < 0.05, **P* < 0.01 and ***P* < 0.001. Significant factors for the whole experiment given in the upper panel (see Table 1 for full results) and for Si- and Si+ plants separately in the respective graphical panels.

**Fig. 2.** Impacts of CO\(_2\), temperature and aphid presence on root nodulation (number per plant) of *M. sativa* when growing in (A) non-supplemented and (B) Si supplemented soil. Mean values ± standard error shown (N = 20) with statistically significant effects indicated *P* < 0.05, **P* < 0.01 and ***P* < 0.001. Significant factors shown as per Fig. 1 legend.

**Fig. 3.** Impacts of CO\(_2\), temperature and aphid presence on Si concentrations of *M. sativa* foliage (% dry mass) when growing in (A) non-supplemented and (B) Si supplemented soil. Mean values ± standard error shown (N = 9) with statistically significant effects indicated ***P* < 0.001. Significant factors shown as per Fig. 1 legend.

**Fig. 4.** Impacts of CO\(_2\) and temperature on aphid (*A. pisum*) abundance (number per plant) when feeding on *M. sativa* plants growing in (A) non-supplemented and (B) Si supplemented soil. Mean values ± standard error shown (N = 20) with statistically significant effects indicated ***P* < 0.001. Significant factors shown as per Fig. 1 legend.

**Fig. 5.** Graphical summary showing how Si supplementation affects *M. sativa* growth, root nodulation and susceptibility to *A. pisum* in current and predicted changes to the climate and atmosphere. Compared with ambient CO\(_2\) and temperature conditions (panel A), eCO\(_2\) had beneficial effects on plant growth and nodulation (panel B), but these were negated when acting in combination with predicted increases in temperature (panel C). Si supplementation (panel D) restored root nodulation to comparable levels as those seen under eCO\(_2\) conditions (without warming) and stimulated plant growth beyond this. Aphid responses were decoupled from changes in nodulation and growth with Si supplementation.
Table 1. Results of statistical tests examining the effects of CO\(_2\), temperature (Temp), aphid presence and Si supplementation (Si) on plant growth, root nodulation, and foliar Si concentrations. Statistically significant (\(P < 0.05\)) factors indicated in **bold** with Fisher’s (F) or residual deviation (RD) given depending on the models used. Analysis conducted on transformed data as indicated.

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<th>Plant response</th>
<th>Dry mass(^1)</th>
<th>Root Nodules</th>
<th>Si Concentration(^1)</th>
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<tr>
<td></td>
<td>(F_{1,304})</td>
<td>(P)</td>
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<td>CO(_2) × Temp × Aphids × Si</td>
<td>0.06</td>
<td>0.81</td>
<td>332.95</td>
</tr>
</tbody>
</table>

\(^1\)Log transformed. Degrees of freedom in each column apply to all effects.
**Table 2.** Results of statistical tests examining the effects of CO$_2$, temperature and Si supplementation on aphid abundance and colonisation success. Statistically significant ($P < 0.05$) indicated in **bold** with residual deviation (RD) given.

<table>
<thead>
<tr>
<th>Plant response</th>
<th>Model fixed effect</th>
<th>Aphid abundance</th>
<th>Aphid colonisation</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>RD$_{1,159}$</td>
<td>$P$</td>
</tr>
<tr>
<td>CO$_2$</td>
<td></td>
<td>177.62</td>
<td>0.16</td>
</tr>
<tr>
<td>Temp</td>
<td></td>
<td><strong>162.39</strong></td>
<td><strong>&lt;0.001</strong></td>
</tr>
<tr>
<td>Si</td>
<td></td>
<td>160.42</td>
<td>0.16</td>
</tr>
<tr>
<td>CO$_2$ × Temp</td>
<td></td>
<td>160.24</td>
<td>0.68</td>
</tr>
<tr>
<td>CO$_2$ × Si</td>
<td></td>
<td>160.24</td>
<td>0.93</td>
</tr>
<tr>
<td>Temp × Si</td>
<td></td>
<td>160.03</td>
<td>0.65</td>
</tr>
<tr>
<td>CO$_2$ × Temp × Si</td>
<td></td>
<td>159.91</td>
<td>0.73</td>
</tr>
</tbody>
</table>
Figure 1

**CO₂*** **Temperature**

**Aphids** **Silicon***

**CO₂ x Silicon**

**CO₂ x Temperature x Silicon**

---

(A) **CO₂*** **Temperature***

(B) **Aphids** **CO₂ x Temperature**

![Bar charts showing dry mass (mg) for different treatments and conditions.](Figure 1.TIF)

- **Control**
- **Aphids**
- **Ambient CO₂**
- **Elevated CO₂**

Treatments

In review
Figure 2.TIF

CO₂ **  Temperature ***  Silicon ***  Temperature x Silicon *

(A) CO₂ ***
Temperature ***
CO₂ x Aphids *

Unsupplemented

(B) Silicon supplemented

Root nodules

<table>
<thead>
<tr>
<th>Treatments</th>
<th>26°C</th>
<th>30°C</th>
</tr>
</thead>
<tbody>
<tr>
<td>CONTROL</td>
<td></td>
<td></td>
</tr>
<tr>
<td>APHIDS</td>
<td></td>
<td></td>
</tr>
<tr>
<td>CONTROL</td>
<td></td>
<td></td>
</tr>
<tr>
<td>APHIDS</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

ambient CO₂

elevated CO₂
Silicon***

(A) Unsupplemented

(B) Silicon supplemented

Treatments

![Chart showing the effect of silicon supplementation and aphid attack on silicon levels at different temperatures and CO2 levels.

- CONTROL
- APHIDS

Levels:
- ambient CO2
- elevated CO2

Temperature:
- 26°C
- 30°C

Silicon levels measured in plants under different conditions.
Figure 4.

Temperature:

(A) Unsupplemented

(B) Silicon supplemented

Aphids

Temperature

26°C  30°C

Treatments

ambient CO₂
elevated CO₂